GU1A THRU GU1M

SURFACE MOUNT SWITCHING RECTIFIER

VOLTAGE: 50 TO 1000V CURRENT: 1.0A



FEATURE

Ideal for surface mount pick and place application Low profile package

Built-in strain relief

High surge capability

High temperature soldering guaranteed

260 ℃/10sec/at terminals Glass passivated chip

Fast recovery time for high efficiency

MECHANICAL DATA

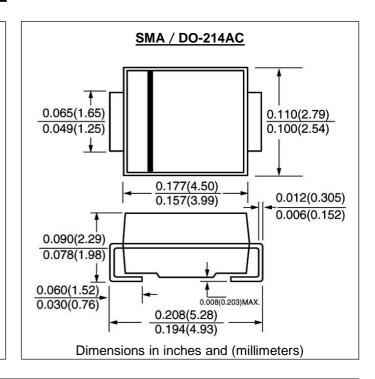
Terminal: Plated axial leads solderable per

MIL-STD 202E, method 208C

Case: Molded with UL-94 class V-0 recognized Flame

Retardant Epoxy

Polarity: color band denotes cathode



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(single-phase, half-wave, 60HZ, resistive or inductive load rating at 25°C, unless otherwise stated, for capacitive load, derate current by 20%)

	SYMBOL	GU 1A	GU 1B	GU 1D	GU 1G	GU 1J	GU 1K	GU 1M	units
Maximum Recurrent Peak Reverse Voltage	Vrrm	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	Vrms	35	70	140	280	420	560	700	V
Maximum DC blocking Voltage	Vdc	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current 3/8 ″ lead length at T _L =110 °C	If(av)	1.0							А
Peak Forward Surge Current 8.3ms single half sine- wave superimposed on rated load	Ifsm	30.0						А	
Maximum Forward Voltage at rated forward current	Vf	1.0			1.4	1.7			V
Maximum DC Reverse Current Ta =25°C	Ir	lr 10.0							μА
at rated DC blocking voltage Ta =100°C		500.0							μА
Maximum Reverse Recovery Time (Note1)	Trr	50				75			nS
Typical Junction Capacitance (Note 2)	Cj	15.0						pF	
Typical Thermal Resistance (Note 3)	R(jl)	30.0						°C/W	
Storage and Operating Junction Temperature	Tstg, Tj	-50 to +150							$^{\circ}$ C

Note:

- 1. Reverse Recovery Condition If =0.5A, Ir =1.0A, Irr =0.25A
- 2. Measured at 1.0 MHz and applied reverse voltage of 4.0Vdc
- 3. Thermal Resistance from Junction to terminal mounted on 5×5mm copper pad area1

¹Rev.A5 www.gulfsemi.com

Fig. 1 - Forward Current **Derating Curve** Resistive or Inductive Load 1.0 Average Forward Current (A) GU1A-GU1J 0.8 GU1K-GU1M 0.6 0.4 0.2 0.2 x 0.2" (5.0 x 5.0mm) Thick Copper Pad Areas 0 0 20 40 60 80 100 120 140 160 Lead Temperature (°C)

FIG. 3 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

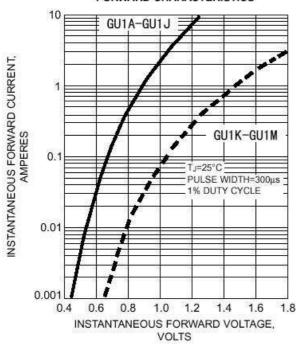


FIG. 5 - TYPICAL JUNCTION CAPACITANCE

TJ=25°C
f=1.0 MHz
Vsig=50mVp-p
10
1
1
1
1
1
1
1
1
1
REVERSE VOLTAGE, VOLTS

Fig. 2 – Maximum Non-Repetitive Peak Forward Surge Current

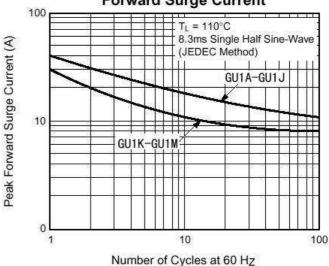
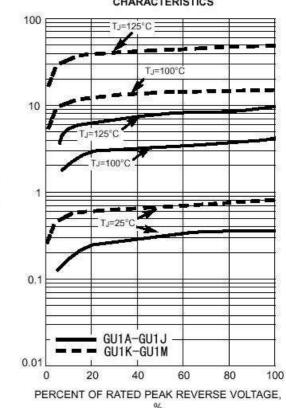


FIG. 4 - TYPICAL REVERSE LEAKAGE CHARACTERISTICS



INSTANTANEOUS REVERSE LEAKAGE CURRENT, MICROAMPERES

² Rev.A5 www.gulfsemi.com

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